VS-85HF(R)40M8

Vishay Semiconductors



Standard Recovery Diodes, (Stud Version), 85 A



DO-203AB (DO-5)

PRODUCT SUMMARY			
I _{F(AV)}	85 A		
Package	DO-203AB (DO-5)		
Circuit configuration Single diode			

FEATURES

- High surge current capability
- Stud cathode and stud anode version
- Leaded version available
- Types up to 400 V V_{RRM}
- Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- Battery chargers
- Converters
- Power supplies
- Machine tool controls
- Welding

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	85HF(R)	UNITS	
		400		
I _{F(AV)}		85	A	
	T _C	140	°C	
I _{F(RMS)}		133	A	
I _{FSM}	50 Hz	1700	Α	
	60 Hz	1800	A	
l ² t	50 Hz	14 500	A ² s	
	60 Hz	13 500	A-S	
V _{RRM}	Range	400	V	
TJ		-65 to 180	°C	

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE NUMBER	VOLTAGE CODE	V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} MAXIMUM AT T _J = T _J MAXIMUM mA	
VS-85HF(R)	40	400	500	9	

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FORWARD CONDUCTION							
PARAMETER	SYMBOL	TEST CONDITIONS			85HF(R)	UNITS	
Maximum average forward current	I _{F(AV)}	180° conduction, half sine wave		85	A		
at case temperature	1 (44)				140	°C	
Maximum RMS forward current	I _{F(RMS)}				133	A	
		t = 10 ms	No voltage		1700		
Maximum peak, one-cycle forward, non-repetitive		t = 8.3 ms	reapplied		1800	A	
surge current	I _{FSM}	t = 10 ms	100 % V _{RRM}		1450		
		t = 8.3 ms	reapplied	Sinusoidal half wave, initial T _J = T _J maximum	1500		
	l ² t	t = 10 ms	No voltage		14 500	A ² s	
Maximum 12t for fusing		t = 8.3 ms	reapplied		13 500		
Maximum I ² t for fusing		t = 10 ms	100 % V _{RRM}		10 500		
		t = 8.3 ms	reapplied		9400		
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied			16 000	A²√s	
Value of threshold voltage (up to 1200 V)		T _J = T _J maximum		T. T. marine		0.68	v
Value of threshold voltage (for 1400 V, 1600 V)	V _{F(TO)}			0.69			
Value of forward slope resistance (up to 1200 V)	- r _f	T _J = T _J maximum				1.62	mW
Value of forward slope resistance (for 1400 V, 1600 V)				1.75	11100		
Maximum forward voltage drop	V _{FM}	$I_{pk} = 267 \text{ A}, T_J = 25 \text{ °C}, t_p = 400 \mu\text{s}$ rectangular wave			1.2	V	

THERMAL AND MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	DL TEST CONDITIONS 85HF(R)		UNITS
Maximum junction operating and storage temperature range	T _J , T _{Stg}		-65 to 180	°C
Maximum thermal resistance, junction to case R _{thJC}		DC operation 0.35		К/W
Maximum thermal resistance, case to heatsink		Mounting surface, smooth, flat and greased	0.25	1// 1/
		Not lubricated thread, tighting on nut	3.4 (30)	
Maximum allowable mounting targue + 0.0/ 10.0/		Lubricated thread, tighting on nut	2.3 (20)	N⋅m
Maximum allowable mounting torque + 0 %, - 10 %		Not lubricated thread, tighting on hexagon	4.2 (37)	(lbf · in)
		Lubricated thread, tighting on hexagon	3.2 (28)	
Approvimete weight		Unleaded device	17	g
Approximate weight			0.6	oz.
Case style		See dimensions - link at the end of datasheet DO-203AB (DO-5		8 (DO-5)

CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.10	0.08		
120°	0.11	0.11		
90°	0.13	0.13	$T_J = T_J maximum$	K/W
60°	0.17	0.17		
30°	0.26	0.26		

Note

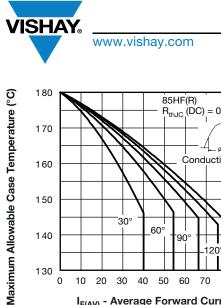
• The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

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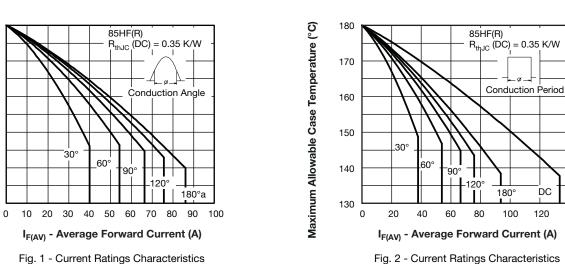
170

160

150

140

130



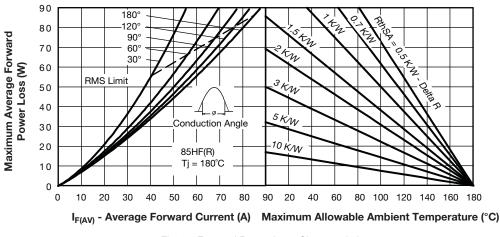
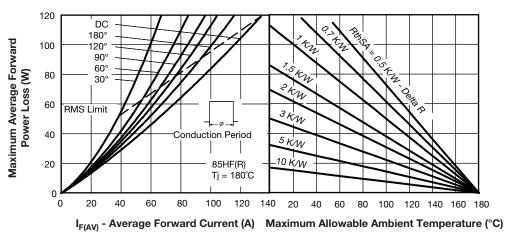
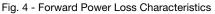


Fig. 3 - Forward Power Loss Characteristics







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Fig. 8 - Thermal Impedance ZthJC Characteristics

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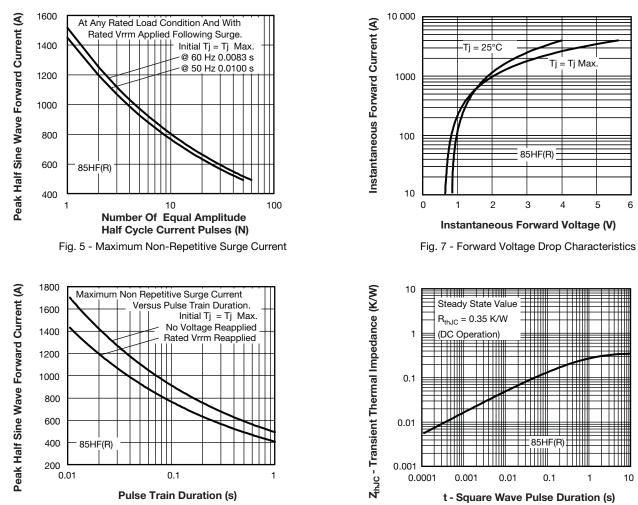
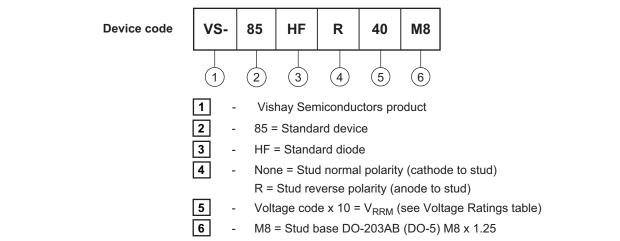


Fig. 6 - Maximum Non-Repetitive Surge Current

ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95342			
Revision: 12-Feb-14	4	Document Number: 93529		
For technical questions within your region: <u>DiodesAmericas@vishay.com</u> , <u>DiodesAsia@vishay.com</u> , <u>DiodesEurope@vishay.com</u>				
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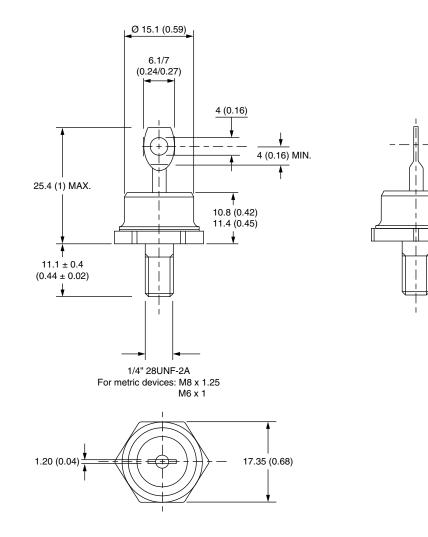
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DO-203AB (DO-5) for 85HF(R) and 86HF(R) Series

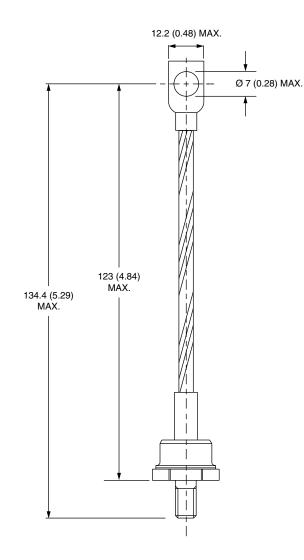
DIMENSIONS in millimeters (inches)



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DIMENSIONS FOR 86HF (R) SERIES in millimeters (inches)





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